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TRANSISTORS, SWITCHING, PNP

BASED ON TYPE 2N3637

ESCC Detail Specification No. 5208/003

Issue 3 January 2010	
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ESCC Detail Specification No. 5208/003



ISSUE 3

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1. GENERAL

1.1 SCOPE

This specification details the ratings, physical and electrical characteristics and test and inspection data for the component type variants and/or the range of components specified below. It supplements the requirements of, and shall be read in conjunction with, the ESCC Generic Specification listed under Applicable Documents.

1.2 APPLICABLE DOCUMENTS

The following documents form part of this specification and shall be read in conjunction with it:

- (a) ESCC Generic Specification No. 5000
- (b) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices

1.3 TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESCC Basic Specification No. 21300 shall apply.

1.4 THE ESCC COMPONENT NUMBER AND COMPONENT TYPE VARIANTS

1.4.1 <u>The ESCC Component Number</u>

The ESCC Component Number shall be constituted as follows:

Example: 520800301

Detail Specification Reference: 5208003

Component Type Variant Number: 01 (as required)

1.4.2 <u>Component Type Variants</u>

The component type variants applicable to this specification are as follows:

Variant Number	Based on Type	Case	Lead/Terminal Material and Finish	Weight max g
01	2N3637	TO-5	D2	1.2
02	2N3637	TO-5	D3 or D4	1.2
03	2N3637	TO-39	D2	1.2
04	2N3637	TO-39	D3 or D4	1.2

The lead/terminal material and finish shall be in accordance with the requirements of ESCC Basic Specification No. 23500.

1.5 MAXIMUM RATINGS

The maximum ratings shall not be exceeded at any time during use or storage.



Maximum ratings shall only be exceeded during testing to the extent specified in this specification and when stipulated in Test Methods and Procedures of the ESCC Generic Specification.

Characteristics	Symbols	Maximum Ratings	Unit	Remarks
Collector-Base Voltage	V _{CBO}	175	V	Over entire
Collector-Emitter Voltage	V _{CEO}	175	V	operating temperature
Emitter-Base Voltage	V _{EBO}	-5	V	range
Collector Current	I _C	1	Α	Continuous
Power Dissipation	P _{tot1}	1	W	At T _{amb} ≤ +25°C
	P _{tot2}	5	W	At T _{case} ≤ +25°C
Thermal Resistance, Junction-to-Ambient	R _{th(j-a)}	175	°C/W	
Thermal Resistance, Junction-to-Case	R _{th(j-c)}	35	°C/W	
Operating Temperature Range	T _{op}	-65 to +200	°C	Note 1
Storage Temperature Range	T _{stg}	-65 to +200	°C	Note 1
Soldering Temperature	T _{sol}	+265	°C	Note 2

NOTES:

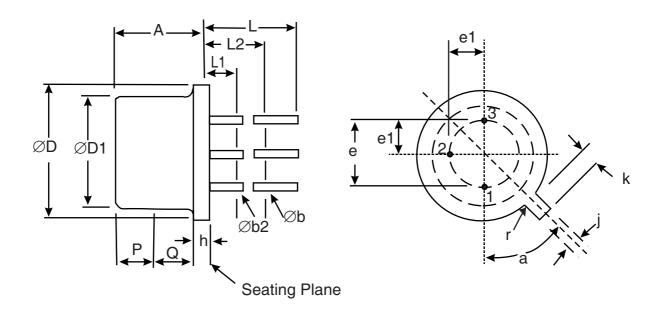
- 1. For Variants with tin-lead plating or hot solder dip lead finish all testing, and any handling, performed at $T_{amb} > +125^{\circ}C$ shall be carried out in a 100% inert atmosphere.
- 2. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.

1.6 PHYSICAL DIMENSIONS AND LEAD IDENTIFICATION

Consolidated notes are given following the case drawings and dimensions.



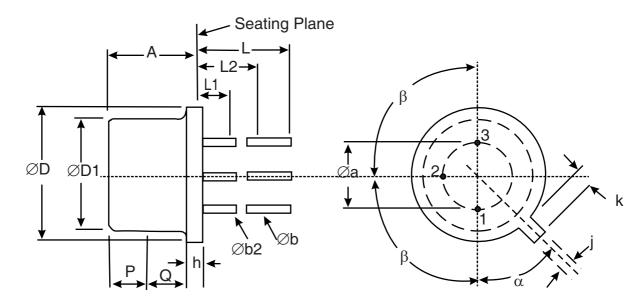
1.6.1 <u>Metal Can Package (TO-5) - 3 lead</u>



Symbols	Dimensio	Notes	
Symbols	Min	Max	Notes
Α	6.1	6.6	
Øb	0.406	0.533	2, 3
Øb2	0.406	0.483	2, 3
ØD	8.51	9.4	
ØD1	7.75	8.51	
е	5.08	BSC	7
e1	2.54 BSC		
h	0.229	3.18	
j	0.711	0.864	
k	0.737	1.14	5
L	38.1	-	2
L1	-	1.27	2, 3
L2	6.35	-	2, 3
Р	2.54	-	6
Q	-	-	8
r	-	0.179	
а	45° E	BSC	1, 9



1.6.2 Metal Can Package (TO-39) - 3 lead



Symbols	Dimension	Notes	
Symbols	Min	Max	Notes
Øa	4.83	5.35	
Α	6	6.6	
Øb	0.4	0.533	2, 4
Øb2	0.4	0.483	2, 4
ØD	8.31	9.4	
ØD1	7.75	8.51	6
h	0.229	3.18	
j	0.711	0.864	
k	0.737	1.14	5
L	12.7	19	2
L1	-	1.27	2, 4
L2	6.35	-	2, 4
Р	2.54	-	6
Q	-	-	8
α	45° BSC		1, 9
β	90° E	BSC	1

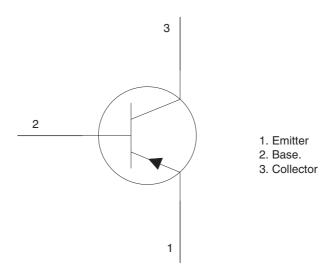
1.6.3 <u>Notes to Physical Dimensions and Terminal Identification</u>

- 1. Terminal identification is specified by reference to the tab position where Lead 1 = emitter, Lead 2 = base and Lead 3 = collector.
- 2. Applies to all leads.
- 3. Øb2 applies between L1 and L2. Øb applies between L2 and 38.1mm from the seating plane. Diameter is uncontrolled within L1 and beyond 38.1mm from the seating plane.
- 4. Øb2 applies between L1 and L2. Øb applies between L2 and 12.7mm from the seating plane.



- Diameter is uncontrolled within L1 and beyond 12.7mm from the seating plane.
- 5. Measured from the maximum diameter of the actual device.
- 6. This zone is controlled for automatic handling. The variation in actual diameter within this zone shall not exceed 0.254mm.
- 7. Leads having maximum diameter 0.483mm measured in the gauging plane 1.37 (+0.025, -0)mm below the seating plane of the device shall be within 0.178mm of their true position relative to a maximum-width-tab.
- 8. The details of outline in this zone are optional.
- 9. Measured from the tab centreline.

1.7 <u>FUNCTIONAL DIAGRAM</u>



NOTES:

1. The collector is internally connected to the case.

1.8 MATERIALS AND FINISHES

Materials and finishes shall be as follows:

- a) Case
 - The case shall be hermetically sealed and have a metal body with hard glass seals.
- b) Leads/Terminals
 - As specified in Component Type Variants.

2. REQUIREMENTS

2.1 GENERAL

The complete requirements for procurement of the components specified herein are as stated in this specification and the ESCC Generic Specification. Permitted deviations from the Generic Specification, applicable to this specification only, are listed below.

Permitted deviations from the Generic Specification and this Detail Specification, formally agreed with



specific Manufacturers on the basis that the alternative requirements are equivalent to the ESCC requirement and do not affect the component's reliability, are listed in the appendices attached to this specification.

2.1.1 Deviations from the Generic Specification

None.

2.2 MARKING

The marking shall be in accordance with the requirements of ESCC Basic Specification No. 21700 and as follows.

The information to be marked on the component shall be:

- (a) The ESCC qualified components symbol (for ESCC qualified components only).
- (b) The ESCC Component Number.
- (c) Traceability information.

2.3 TERMINAL STRENGTH

The test conditions for terminal strength, tested as specified in the ESCC Generic Specification, shall be as follows:

Test Condition: E, lead fatigue.

2.4 ELECTRICAL MEASUREMENTS AT ROOM, HIGH AND LOW TEMPERATURES

Electrical measurements shall be performed at room, high and low temperatures.

2.4.1 <u>Room Temperature Electrical Measurements</u>

The measurements shall be performed at T_{amb} =+22 ±3°C.

Characteristics	Symbols	MIL-STD-750	Test Conditions	Lin	nits	Units
		Test Method	Test Method		Max	
Collector-Base Breakdown Voltage	V _{(BR)CBO}	3001	I _E = -100μA Bias condition D	-175	-	V
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	3011	I _C = -10mA Bias condition D Note 1	-175	-	V
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	3026	I _E = -10μA Bias condition D	-5	-	V
Collector-Base Cut-off Current	I _{CBO}	3036	V _{CB} = -100V Bias condition D	-	-100	nA
Emitter-Base Cut- off Current	I _{EBO}	3061	V _{EB} = -3V Bias condition D	-	-50	nA

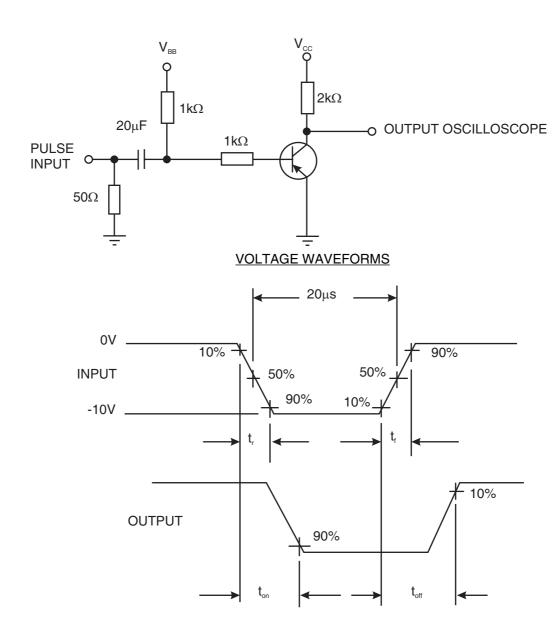


Characteristics	Symbols	MIL-STD-750	Test Conditions	Lin	nits	Units
		Test Method		Min	Max	
Forward-Current Transfer Ratio	h _{FE1}	3076	V _{CE} =-10V I _C =-50mA Note 1	100	300	-
	h _{FE2}	3076	V _{CE} =-10V I _C =-150mA Note 1	50	-	-
Collector-Emitter Saturation Voltage	V _{CE(sat)}	3071	I _C =-50mA I _B =-5mA Note 1	-	-500	mV
Base-Emitter Saturation Voltage	V _{BE(sat)}	3066	I _C =-50mA I _B =-5mA Test Condition A Note 1	-650	-900	mV
Turn-on Time	t _{on}	-	V_{CC} =-100V V_{BB} =4V I_{C} =-50mA I_{B} =-5mA Note 2	-	400	ns
Turn-off Time	t _{off}	-	V_{CC} =-100V V_{BB} =4V I_{C} =-50mA I_{B} =-5mA Note 2	-	600	ns

NOTES:

- 1. Pulsed measurement: Pulse Width $\leq 300 \mu s$, Duty Cycle $\leq 2\%$.
- 2. t_{on} and t_{off} shall be measured, on a read and record basis, on a sample of 32 components with 0 failures allowed. Alternatively a 100% inspection may be performed. The measurements shall be made using the following test circuit. The input waveform shall be supplied by a pulse generator with the following characteristics: $Z_{out} = 50\Omega$, $t_r = t_f \le 15$ ns, Pulse Width = 20μ s, Duty Cycle $\le 2\%$. The output shall be monitored on an oscilloscope with the following characteristics: $Z_{in} \ge 10M\Omega$, $t_r \le 15$ ns, $C_{in} \le 11.5$ pF.





2.4.2 <u>High and Low Temperatures Electrical Measurements</u>

Characteristics	Symbols	MIL-STD-750	Test Conditions	Lin	nits	Units
		Test Method	Note 1	Min	Max	
Collector-Base Cut-off Current	I _{CBO}	3036	T _{amb} =+125 (+0 -5)°C V _{CB} =-100V Bias condition D	-	-100	μА
Forward-Current Transfer Ratio 1	h _{FE1}	3076	T _{amb} =-55 (+5-0)°C I _C =-50mA V _{CE} =-10V Note 2	50	300	-



NOTES:

- 1. Read and record measurements shall be performed on a sample of 5 components with 0 failures allowed. Alternatively a 100% inspection may be performed.
- 2. Pulsed measurement: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.

2.5 PARAMETER DRIFT VALUES

Unless otherwise specified, the measurements shall be performed at T_{amb} =+22 $\pm 3^{o}$ C.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements.

The drift values (Δ) shall not be exceeded for each characteristic specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

Characteristics	Symbols		Units			
	Drift				olute	
		Value ∆	Min	Max		
Collector-Base Cut-off Current	I _{CBO}	±30 or (1) ±100%	-	-100	nA	
Forward-Current Transfer Ratio 1	h _{FE1}	±15%	100	300	-	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	±75 or (1) ±15%	-	-500	mV	

NOTES:

Whichever is the greater referred to initial value.

2.6 <u>INTERMEDIATE AND END-POINT ELECTRICAL MEASUREMENTS</u>

Unless otherwise specified, the measurements shall be performed at T_{amb} =+22 ±3°C.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements.

The limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits		Units
		Min	Max	
Collector-Base Cut-off Current	I _{CBO}	-	-100	nA
Forward-Current Transfer Ratio 1	h _{FE1}	100	300	-
Collector-Emitter Saturation Voltage	V _{CE(sat)}	-	-500	mV



2.7 <u>HIGH TEMPERATURE REVERSE BIAS BURN-IN CONDITIONS</u>

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T _{amb}	+150 (+0 -5)	°C
Collector-Emitter Voltage	V _{CE}	50	V
Duration	t	48 minimum	Hours

2.8 <u>POWER BURN-IN CONDITIONS</u>

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T _{amb}	+22 ±3	°C
Power Dissipation	P _{tot}	1	W
Collector-Emitter Voltage	V _{CE}	-50	V

2.9 <u>OPERATING LIFE CONDITIONS</u>

The conditions shall be as specified for Power Burn-in.